

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

JAN 23 2004

In Re: Application of REN, et al.

Serial No.: 10/649,712

Examiner:

Date Filed: August 26, 2003

Group: 2812

For: GAN-TYPE ENHANCEMENT MOSFET USING HETERO STRUCTURE

CERTIFICATE UNDER 37 CFR 1.8(a)

I hereby certify that this correspondence is being deposited with the U.S. Postal Service as First Class mail in an envelope addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on

1/20/04
Neil R. Jetter, Esq. Reg. No. 46,803

TRANSMITTAL LETTER

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Please find enclosed for filing the following:

X Supplemental Information Disclosure Statement, with PTO/SB/08A and PTO/SB/08B, and references; and

X 1 postcard.

Although no fee is believed due, please charge any underpayment to Deposit Account No.

50-0951. This letter is submitted in duplicate.

Respectfully submitted,

AKERMAN SENTERFITT

Dated: 1/20/04

Neil R. Jetter, Esq.
Registration No. 46,803
222 Lakeview Avenue, Suite 400
West Palm Beach, FL 33402-3188
Tel: 561-653-5000

Docket No. 5853-274